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(71) Applicant: **OVONYX, INC. [US/US]**; 1090 Boeing Street, Boise, ID 83705 (US).

(72) Inventor: **LOWREY, Tyler, A.**; 516 Mill River Lane, San Jose, CA 95134 (US).

(74) Agents: **TROP, Timothy, N. et al.; TROP, PRUNER & HU, P.C.**, 8554 Katy Freeway, Suite 100, Houston, TX 77024 (US).

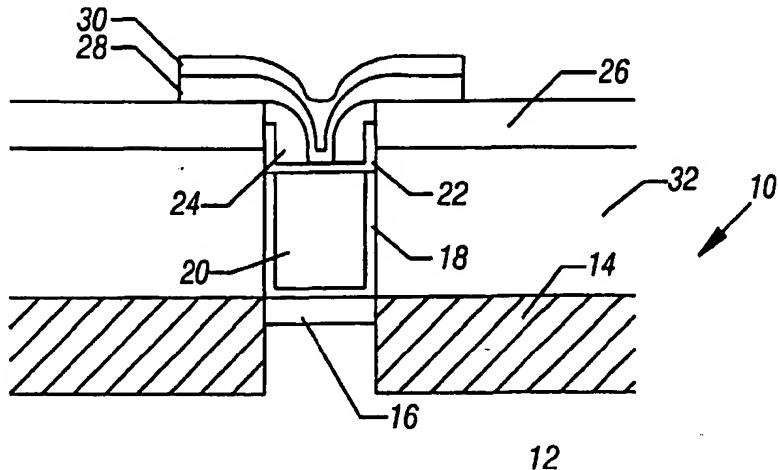
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(54) Title: ELEVATED PORE PHASE-CHANGE MEMORY



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(57) Abstract: An elevated phase-change memory cell (10) facilitates manufacture of phase-change memories by physically separating the fabrication of the phase-change memory components from the rest of the semiconductor substrate (12). In one embodiment, a contact (16) in the substrate (12) may be electrically coupled to a cup-shaped conductor (18) filled with an insulator (20). The conductor (18) couples current up to the elevated pore while the insulator (20) thermally and electrically isolates the pore.